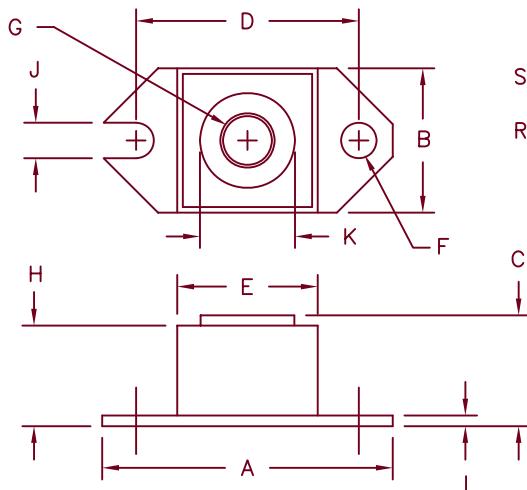


180 Amp Schottky Rectifier

HS18135–HS18145



Std. Polarity
Base is cathode
Rev. Polarity
Base is anode

Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	1.52	1.56	38.61	39.62	
B	.725	.775	18.42	19.69	
C	.605	.625	15.37	15.88	
D	1.182	1.192	30.02	30.28	
E	.745	.755	18.92	19.18	Sq.
F	.152	.160	3.86	4.06	Dia.
G			1/4-20 UNC-2B		
H	.545	.580	13.84	14.73	
J	.156	.160	3.96	4.06	
K	.495	.505	12.57	12.83	Dia.
L	.120	.130	3.05	3.30	

HALF-PAK

Microsemi Catalog Number	Industry Part Number	Working Reverse Voltage	Peak Reverse Voltage	Repetitive Peak Reverse Voltage
HS18135*	181NQ035	35V	35V	
HS18140*	181NQ040	40V	40V	
HS18145*	181NQ045	45V	45V	

* Add Suffix R for Reverse Polarity

- Schottky Barrier Rectifier
- Guard Ring Protection
- Low Forward Voltage
- 175°C Junction Temperature
- V_{RRM} 35–45 Volts
- Reverse Energy Tested

Electrical Characteristics

Average forward current	$I_F(AV)$ 180 Amps	$T_C = 142^\circ C$, square wave, $R_{\theta JC} = 0.3^\circ C/W$
Maximum surge current	I_{FSM} 2500 Amps	8.3ms, half sine, $T_J = 175^\circ C$
Maximum repetitive reverse current	$I_{R(OV)}$ 2 Amps	$f = 1$ kHz, 1us square wave, $T_J = 25^\circ C$
Max peak forward voltage	V_{FM} 0.70 Volts	$I_{FM} = 180A$: $T_J = 25^\circ C^*$
Max peak reverse current	I_{RM} 150mA	V_{RRM} , $T_J = 125^\circ C^*$
Max peak reverse current	I_{RM} 4mA	V_{RRM} , $T_J = 25^\circ C$
Typical junction capacitance	C_J 7500pF	$V_R = 5.0V$, $T_J = 25^\circ C$, $f = 1MHz$

*Pulse test: Pulse width 300 μ sec, Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temp range	T_{STG}	-55°C to 175°C
Operating junction temp range	T_J	-55°C to 175°C
Max thermal resistance	$R_{\theta JC}$	0.3°C/W junction to case
Typical thermal resistance (greased)	$R_{\theta CS}$	0.12°C/W case to sink
Mounting Base Torque		15–25 inch pounds
Terminal Torque		20–40 inch pounds
Weight		1.1 ounces (32 grams) typical

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05-11-07 Rev. 3

HS18135—HS18145

Figure 1
Typical Forward Characteristics

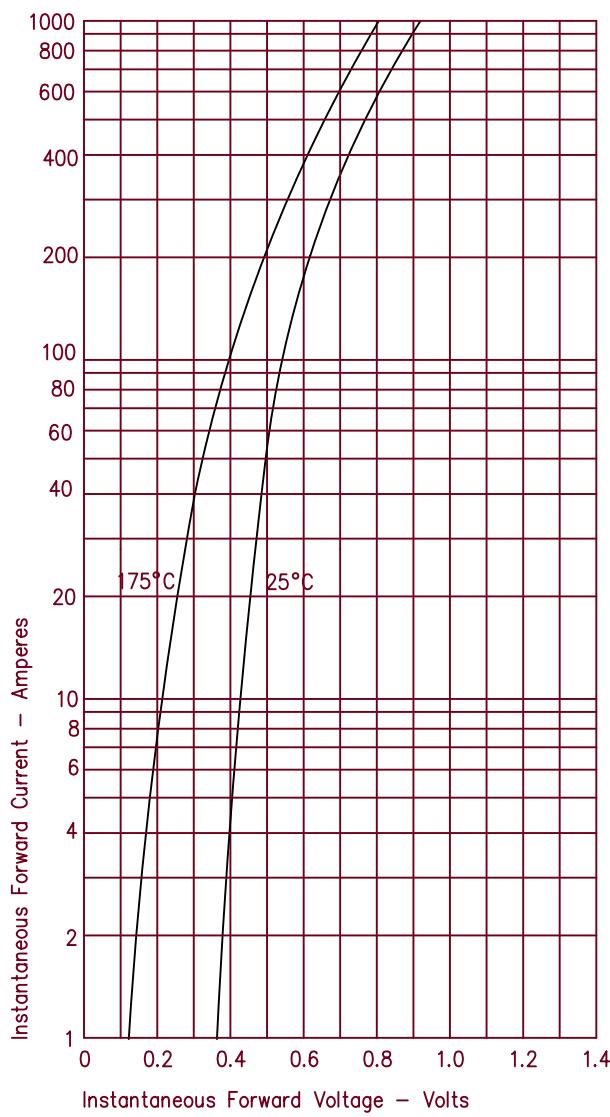


Figure 2
Typical Reverse Characteristics

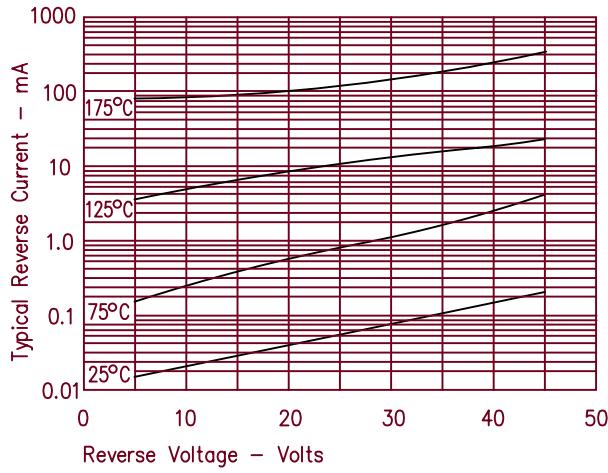


Figure 3
Typical Junction Capacitance

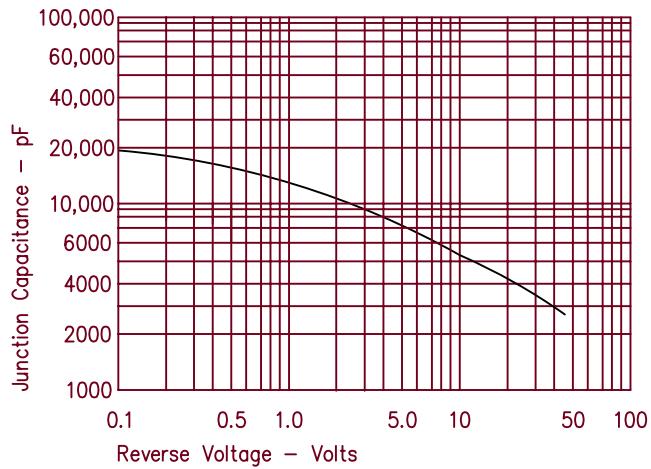


Figure 4
Forward Current Derating

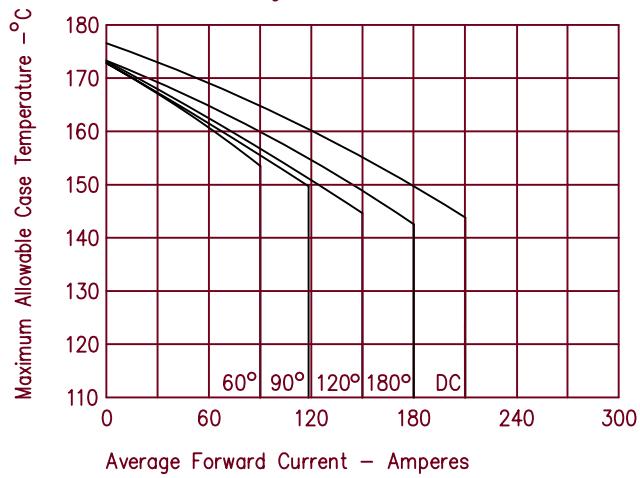


Figure 5
Maximum Forward Power Dissipation

